

SMALL SIGNAL SWITCHING DIODE

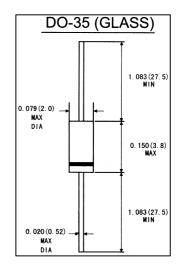
FEATURES

- . Silicon epitaxial planar diode
- . Fast swithching diodes
- . 500mW power dissipation
- . The diode is also available in the Mini-MELF case with the type designation LL4448

MECHANICAL DATA

. Case: MinMelf glass case(SOD- 80)

. Weight: Approx. 0.05gram



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Ratings at 25°C ambient temperature unless otherwise specified)

	Symbol	Value	Units
Reverse voltage	VR	75	Volts
Peak reverse voltage	VRM	100	Volts
Average rectified current, Half wave rectification with	lav	1501)	mA
Resistive load at Ta=25 °C and F≥50Hz			
Surge forward current at t<1S and TJ=25 $^{\circ}\!$	IFSM	500	mW
Power dissipation at Ta=25°C	Ptot	5001)	mW
Junction temperature	TJ	175	$^{\circ}\mathbb{C}$
Storage temperature range	Тѕтс	-65 to + 175	$^{\circ}$

ELECTRICAL CHARACTERISTICS

(Ratings at 25°C ambient temperature unless otherwise specified)

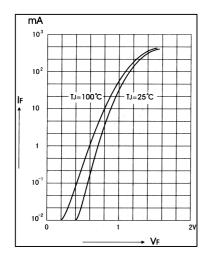
	Symbols	Min.	Тур.	Max.	Units
Forward voltage at IF=5mA	VF	0.62		0.72	V
at IF=10mA	VF			1	V
Leakage current at VR=20V	lr			25	nA
at VR=75V	lr			5	μΑ
at V _R =20V, T _J =150℃	lr			50	μΑ
Junction capacitance at VR=VF=0V	Cı			4	pF
Reverse breakdown voltage tested with 100 A µuse	V(BR)R	100			V
Reverse reco ^μ ry time from IF= μ)mA to IR=1mA,	t	trr		4	ns
VR=6V, RL=100 Ω	CH CH				
Thermal resistance junction to ambient	R⊕ JA			3501)	3501)
Rectification efficience at f=100MHz,VRF=2V	η	0.45			
1)Valid provided that leads at a distance of 8mm from cas	se are kept at ambien	t temperature(I	OO-35)		



RATINGS AND CHATACTERISTIC CURVES LL4448

FLG.1-FORWARD CHARACTERISTICS

FIG.2-DYNAMIC FORWARD RESISTANCE VERSUS FORWARD CURRENT



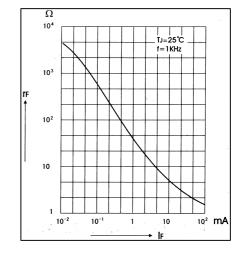
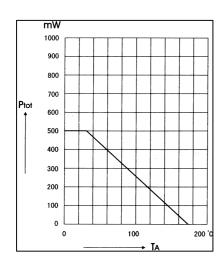
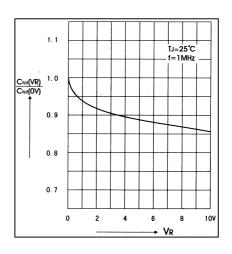


FIG.3-ADMISSIBLE POWER DISSIPATION VERSUS AMBIENT TEMPERATURE

FIG.4-RELATIVE CAPACITANCE VERSUS VOLTAGE







SMALL SIGNAL SWITCHING DIODE

FIG.5-RECTIFICATION EFFICIENCY MEASUREMENT CIRCUIT

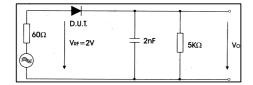


FIG.6-LEAKAGE CURRENT VERSUS JUNCTION TEMPERATURE

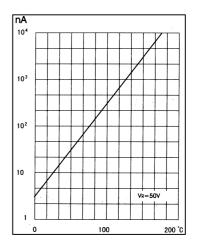


FIG.7-ADMISSIBLE REPETITIVE PEAK FORWARD CURRENT VERSUS PULSE DURATION

